NSN 5961-01-181-9060

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-9060 **Inclosure Material:** Metal **Overall Length:** 1.020 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.127 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 breakdown voltage, dc **Current Rating Per Characteristic:** 200.00 amperes forward current, average peak **Power Rating Per Characteristic:** 1.58 watts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 10.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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